TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSⅢ)

TK40D10J1

Switching Regulator Applications

Unit: mm

• Small gate charge: Q_g = 76nC (typ.)

• Low drain-source ON-resistance: $R_{DS (ON)} = 11.5 \text{ m}\Omega \text{ (typ.)}$

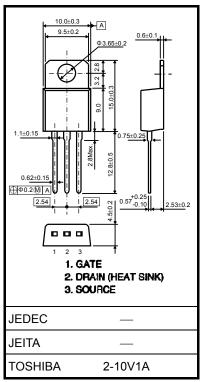
High forward transfer admittance: |Y_{fs}| = 90 S

• Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 100 \text{ V)}$

• Enhancement mode: V_{th} = 1.1 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit	
Drain-source voltage			V_{DSS}	100	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V_{DGR}	100	V	
Gate-source voltage			V_{GSS}	±20	٧	
Drain current	DC	(Note 1)	I _D	40	Α	
	Pulse	(Note 1)	I_{DP}	160	A	
Drain power dissipation (Tc = 25°C)			P_{D}	100	W	
Single pulse avalanche energy (Note 2)			E _{AS}	202	mJ	
Avalanche current			I _{AR}	40	Α	
Repetitive avalanche energy (Note 3)			E _{AR}	5.9	mJ	
Channel temperature			T _{ch}	150	°C	
Storage temperature range			T _{stg}	–55 to 150	°C	



Weight: 1.35 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	1.25	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

Internal Connection



Note 1: Ensure that the channel and lead temperatures do not exceed 150°C.

Note 2: $V_{DD} = 25 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$, $L = 200 \ \mu\text{H}$, $I_{AR} = 40 \ \text{A}$, $R_G = 1 \Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

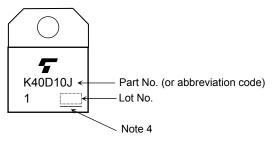
Electrical Characteristics (Ta = 25°C)

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Drain cut-off curre	ent	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V	_	_	10	μΑ
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	100	_	_	V
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	60	_	_	
Gate threshold vo	ltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	1.1	_	2.3	V
Drain-source ON resistance		R _{DS} (ON)	$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{A}$	_	13	17	- mΩ
			$V_{GS} = 10 \text{ V}, I_D = 20 \text{A}$	_	11.5	15	
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 20 A	45	90		S
Input capacitance		C _{iss}		_	4300	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10V, V_{GS} = 0 V, f = 1 MHz$	_	230	_	
Output capacitance		Coss		—	790	_	
Switching time	Rise time	t _r	$\begin{array}{c} 10 \text{ V} \\ \text{VGS} \\ 0 \text{ V} \\ \end{array}$ $\begin{array}{c} \text{I}_D = 20 \text{ A} \\ \text{O V} \\ \text{OUT} \\ \end{array}$ $\begin{array}{c} \text{R}_L = 2.5 \Omega \\ \text{V}_{DD} \simeq 50 \text{ V} \\ \end{array}$ Duty \leq 1%, $t_W = 10 \mu\text{s}$	_	14	_	ns
	Turn-on time	t _{on}		_	22	_	
	Fall time	t _f		_	24		
	Turn-off time	t _{off}		_	115	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq 80 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 40 \text{A}$	_	44		
			$V_{DD} \simeq 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 40 \text{A}$	_	76	_]
Gate-source charge 1		Q _{gs1}		_	11	_	nC
Gate-drain ("miller") charge		Q _{gd}	$V_{DD} \simeq 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 40 \text{A}$	_	21	_	
Gate switch charge		Q _{SW}		_	24	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	_	_	_	40	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	160	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 40 A, V _{GS} = 0 V	_	-0.9	-1.2	٧
Reverse recovery time	t _{rr}	$I_{DR} = 40 \text{ A}, V_{GS} = 0 \text{ V},$	_	55	_	ns
Reverse recovery charge	Qrr	dI _{DR} /dt = 50 A/μs	_	63	_	nC

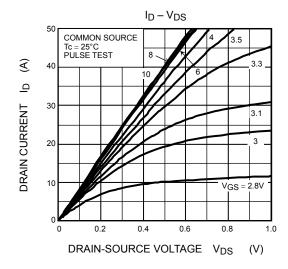
Marking

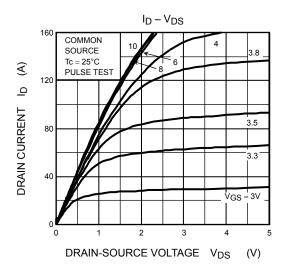


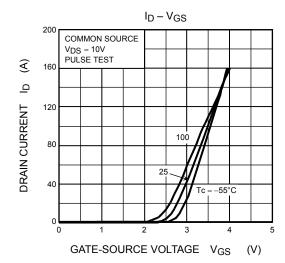
Note 4: A line under a Lot No. identifies the indication of product Labels.

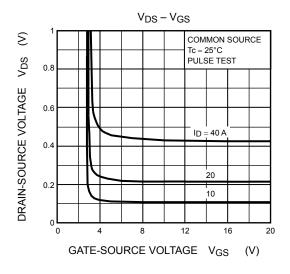
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

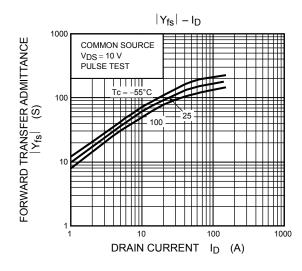
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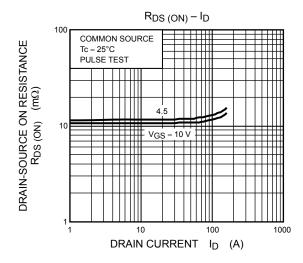


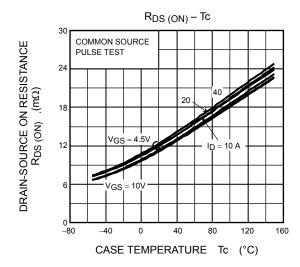


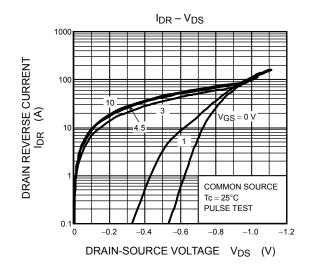


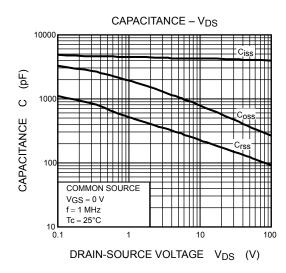


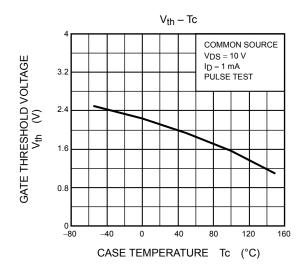


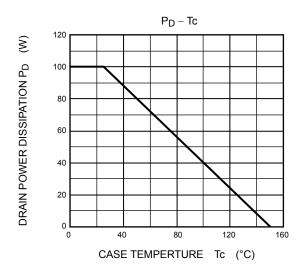


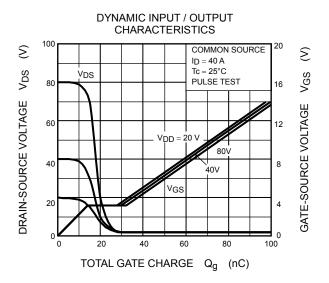


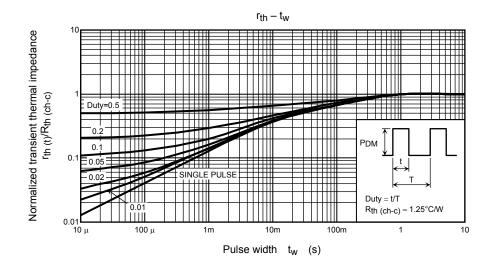


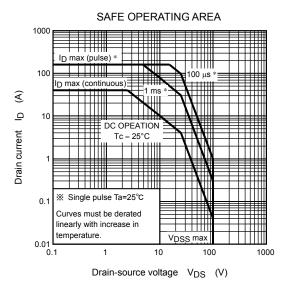


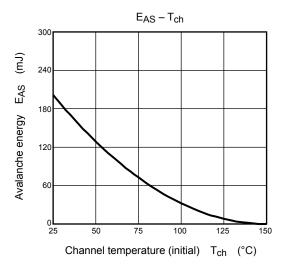


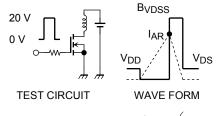












$$\begin{aligned} R_G &= 1 \ \Omega \\ V_{DD} &= 25 \ V, \ L = 200 \ \mu H \end{aligned} \qquad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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